General Purpose Transistor

NPN Silicon

• Moisture Sensitivity Level: 1

• ESD Rating: Human Body Model: >4000 V

Machine Model: >400 V

 NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable

• This is a Pb-Free Device

MAXIMUM RATINGS

| Rating | Symbol | Value | Unit |
|--------------------------------|------------------|-------|------|
| Collector-Emitter Voltage | V_{CEO} | 65 | Vdc |
| Collector-Base Voltage | V_{CBO} | 80 | Vdc |
| Emitter-Base Voltage | V _{EBO} | 6.0 | Vdc |
| Collector Current - Continuous | I _C | 100 | mAdc |

THERMAL CHARACTERISTICS

| Characteristic | Symbol | Max | Unit |
|---|-----------------------------------|----------------|-------------|
| Total Device Dissipation FR-5 Board (Note 1) T _A = 25°C Derate above 25°C | P _D | 265 2.1 | mW mW/°C |
| Derate above 25°C | | 2.1 | IIIVV/°C |
| Thermal Resistance, Junction to Ambient (Note 1) | $R_{	hetaJA}$ | 470 | °C/W |
| Total Device Dissipation Alumina Substrate (Note 2) T _A = 25°C | P _D | 640 | mW |
| Derate above 25°C | | 5.1 | mW/°C |
| Thermal Resistance, Junction to Ambient (Note 2) | $R_{\theta JA}$ | 195 | °C/W |
| Junction and Storage Temperature Range | T _J , T _{stg} | –55 to +150 | °C |

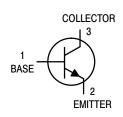
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

- 1. FR-5 = $1.0 \times 0.75 \times 0.062$ in.
- 2. Alumina = $0.4 \times 0.3 \times 0.024$ in. 99.5% alumina.



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MARKING DIAGRAM



SOT-723 CASE 631AA STYLE 1



1B = Specific Device Code M = Date Code

ORDERING INFORMATION

| Device | Package | Shipping [†] |
|----------------|----------------------|-----------------------|
| BC846BM3T5G | SOT-723 (Pb-Free) | 8000 / Tape & Reel |
| NSVBC846BM3T5G | SOT-723 (Pb-Free) | 8000 / Tape & Reel |

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

| Characteristic | Symbol | Min | Тур | Max | Unit |
|--|-----------------------|-----------------|-----------------|-------------------|----------|
| OFF CHARACTERISTICS | • | | • | • | • |
| Collector – Emitter Breakdown Voltage (I _C = 10 mA) | V _(BR) CEO | 65 | - | _ | V |
| Collector – Emitter Breakdown Voltage ($I_C = 10 \mu A, V_{EB} = 0$) | V _(BR) CES | 80 | - | - | V |
| Collector – Base Breakdown Voltage ($I_C = 10 \mu A$) | V _(BR) CBO | 80 | - | - | V |
| Emitter – Base Breakdown Voltage (I _E = 1.0 μA) | V _{(BR)EBO} | 6.0 | - | - | V |
| Collector Cutoff Current $(V_{CB} = 30 \text{ V})$ $(V_{CB} = 30 \text{ V}, T_A = 150^{\circ}\text{C})$ | I _{CBO} | - | - - | 15 5.0 | nA μA |
| ON CHARACTERISTICS | | | | | |
| DC Current Gain $ (I_C = 10 \ \mu\text{A, V}_{CE} = 5.0 \ \text{V}) $ $ (I_C = 2.0 \ \text{mA, V}_{CE} = 5.0 \ \text{V}) $ | h _{FE} | _ 200 | 150 290 | - 450 | _ |
| Collector – Emitter Saturation Voltage (I_C = 10 mA, I_B = 0.5 mA) (I_C = 100 mA, I_B = 5.0 mA) | V _{CE(sat)} | | - - | 0.25 0.6 | V |
| Base – Emitter Saturation Voltage (I_C = 10 mA, I_B = 0.5 mA) (I_C = 100 mA, I_B = 5.0 mA) | V _{BE(sat)} | - | 0.7 0.9 | - - | V |
| Base – Emitter Voltage (I _C = 1.0 mA, V _{CE} = 5.0 V) (I _C = 2.0 mA, V _{CE} = 5.0 V) (I _C = 10 mA, V _{CE} = 5.0 V) | V _{BE(on)} | 550 580 - | 645 660 – | 700 700 770 | mV |
| SMALL-SIGNAL CHARACTERISTICS | | | | | |
| Current – Gain – Bandwidth Product (I _C = 10 mA, V _{CE} = 5.0 Vdc, f = 100 MHz) | f _T | 100 | - | - | MHz |
| Output Capacitance (V _{CB} = 10 V, f = 1.0 MHz) | C _{obo} | - | - | 4.5 | pF |
| Noise Figure (I _C = 0.2 mA, V _{CE} = 5.0 Vdc, R _S = 2.0 k Ω , f = 1.0 kHz, BW = 200 Hz) | NF | _ | - | 10 | dB |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

TYPICAL CHARACTERISTICS

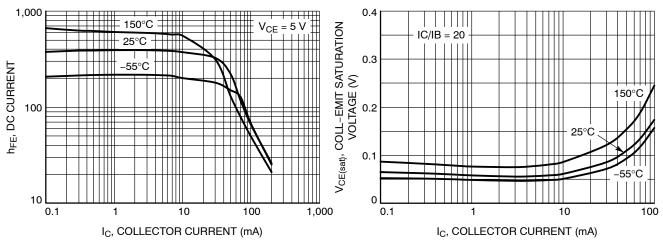


Figure 1. DC Current Gain

Figure 2. Collector-Emitter Saturation Voltage

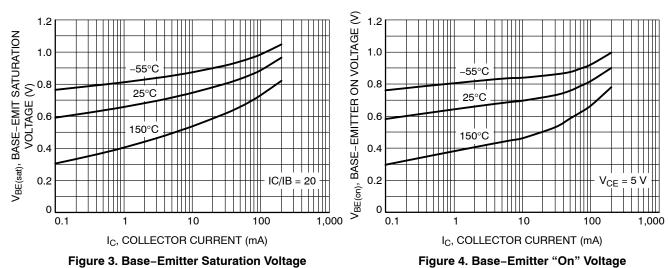


Figure 3. Base-Emitter Saturation Voltage

θ_{VB}, TEMPERATURE COEFFICIENT (mV)

-0.2

-0.6

-1.0

-1.4

-1.8

-2.2

-2.6

0.1

= 5 V

 $\theta_{\mbox{\scriptsize VB}},$ for $\mbox{\scriptsize V}_{\mbox{\scriptsize BE}}$

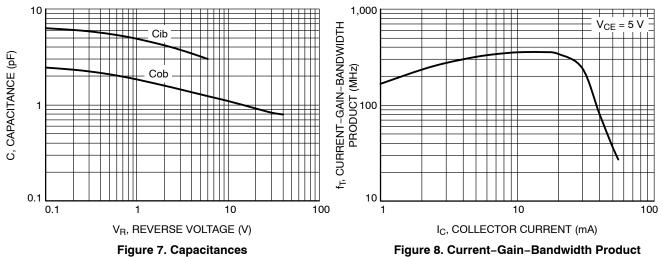
V_{CE}, COLLECTOR-EMITTER VOLTAGE (V) 2.0 = 25°C Î HIIII I_C = 200 mA 10 mA 20 mA 50 mA 100 mA 1.6 1.2 8.0 0.4 0.01 0.1 10 100

IB, BASE CURRENT (mA) Figure 6. Collector Saturation Region

-55°C to 150°C

1,000

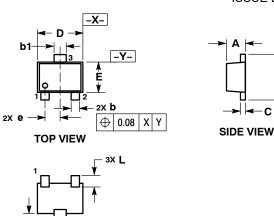
TYPICAL CHARACTERISTICS



PACKAGE DIMENSIONS

SOT-723 CASE 631AA ISSUE D

 H_{E}



BOTTOM VIEW

NOTES:

- DIMENSIONING AND TOLERANCING PER ASME
- Y14.5M, 1994.

 2. CONTROLLING DIMENSION: MILLIMETERS.
- 3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
- 4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS.

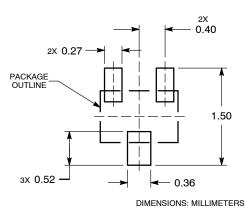
| | MILLIMETERS | | |
|-----|-------------|------|------|
| DIM | MIN | NOM | MAX |
| Α | 0.45 | 0.50 | 0.55 |
| b | 0.15 | 0.21 | 0.27 |
| b1 | 0.25 | 0.31 | 0.37 |
| O | 0.07 | 0.12 | 0.17 |
| D | 1.15 | 1.20 | 1.25 |
| Е | 0.75 | 0.80 | 0.85 |
| е | 0.40 BSC | | |
| ΗE | 1.15 | 1.20 | 1.25 |
| L | 0.29 REF | | |
| L2 | 0.15 | 0.20 | 0.25 |

STYLE 1: PIN 1. BASE

PIN 1. BASE 2. EMITTER

EMITTER
 COLLECTOR

RECOMMENDED SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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